

What is claimed is:

1. A method for forming micropatterns, which comprises irradiating a thin film formed on a substrate with an energy beam to elevate the temperature of a region of the thin film to a predetermined temperature or higher and thereby modify the region of the thin film, and patterning at least the thin film in such a manner to leave over the modified region.

2. A method for forming micropatterns as claimed in Claim 1, wherein the thin film is formed of a metallic film and a resin layer formed on the metallic film, a modified layer insoluble to a development solution is formed in a region of the resin layer whose temperature is elevated to the predetermined temperature or higher by irradiation with the energy beam, and a region of the resin layer other than the modified layer is selectively removed to leave over the modified layer.

3. A method for forming micropatterns as claimed in Claim 1, wherein the thin film is formed of a heat-sensitive multilayer film, a mixed film is formed in a region of the heat-sensitive multilayer film whose temperature is elevated to the predetermined temperature or higher by irradiation with the energy beam, and a region of the heat-sensitive multilayer film other than the mixed film is selectively removed to leave over the mixed layer on the substrate.

4. A method for forming micropatterns as claimed in Claim 1, wherein the thin film is formed of a mask layer and a metallic film formed on the mask layer, a mixed layer is formed of the mask layer and the metallic film at an interface between the mask layer and the

metallic film whose temperature is elevated to the predetermined temperature or higher by irradiation with the energy beam, the metallic film is selectively removed, and a region of the mask layer having no mixed layer formed thereon is selectively etched so that the mixed layer is left over.

5 10 15 20 25 30 35 40 45 50 55 60 65 70 75 80 85 90 95 100 105 110 115 120 125 130 135 140 145 150 155 160 165 170 175 180 185 190 195 200 205 210 215 220 225 230 235 240 245 250 255 260 265 270 275 280 285 290 295 300 305 310 315 320 325 330 335 340 345 350 355 360 365 370 375 380 385 390 395 400 405 410 415 420 425 430 435 440 445 450 455 460 465 470 475 480 485 490 495 500 505 510 515 520 525 530 535 540 545 550 555 560 565 570 575 580 585 590 595 600 605 610 615 620 625 630 635 640 645 650 655 660 665 670 675 680 685 690 695 700 705 710 715 720 725 730 735 740 745 750 755 760 765 770 775 780 785 790 795 800 805 810 815 820 825 830 835 840 845 850 855 860 865 870 875 880 885 890 895 900 905 910 915 920 925 930 935 940 945 950 955 960 965 970 975 980 985 990 995

5. A method for forming micropatterns, which comprises irradiating a thin film formed on a substrate with an energy beam to elevate the temperature of an interface between the thin film and the substrate to a predetermined temperature or higher and thereby form a mixture region of the thin film and the substrate at the interface, and patterning at least the thin film in such a manner to leave over the mixture region.

6. A method for forming micropatterns as claimed in Claim 5, wherein the thin film is formed of a metallic film, a mixed film is formed of the metallic film and the substrate at an interface between the metallic film and the substrate whose temperature is elevated to the predetermined temperature or higher by irradiation with the energy beam, only the metallic film is selectively removed, and a region of the substrate having no mixed film formed thereon is etched by a predetermined amount so that the mixed film and the underlying substrate are left over.

7. A method for forming micropatterns as claimed in Claim 5, wherein the thin film is formed of a metallic film and a transparent film formed on the metallic film, a mixed film is formed of the metallic film and the substrate at an interface between the metallic film and the

substrate whose temperature is elevated to the predetermined temperature or higher by irradiation with the energy beam, the metallic film and the transparent film are selectively removed, and a region of the substrate having no mixed film formed thereon is etched by a predetermined amount so that the mixed film and the underlying substrate are left over.

8. A method for forming micropatterns as claimed in Claim 2, wherein the modified layer is formed in a region smaller than the spot diameter of the irradiated converged optical beam.

9. A method for forming micropatterns as claimed in Claim 2, wherein the metallic film and the resin layer form an antireflection structure with respect to the irradiated converged optical beam.

10. A method for forming micropatterns as claimed in Claim 2, wherein the resin layer is formed of a positive type photoresist.

11. A method for forming micropatterns as claimed in Claim 5, wherein the selective removal of the resin layer other than the modified layer is carried out by using a development solution for the positive type photoresist.

12. A method for forming micropatterns as claimed in Claim 2, further comprising, after leaving over the modified layer on the substrate, etching the metallic film in a region where the modified layer is not formed by use of the modified layer as a mask and selectively removing the modified layer thereafter.

13. A method for forming micropatterns as claimed in Claim 12, wherein said metallic film is etched by dry etching.

14. A method for forming micropatterns as claimed in Claim 12 or 13, wherein the method further comprises, after selectively removing the modified layer, etching the substrate having no metallic film formed thereon by using the metallic film as a mask, and selectively removing
5 the metallic film thereafter.

15. A method for forming micropatterns as claimed in Claim 6 or 7, wherein the method comprises, after etching the region of the substrate having no mixed film formed thereon for the predetermined amount, selectively removing the remaining mixed film by sputter
10 etching.

16. A method for forming micropatterns as claimed in Claim 6 or 7, wherein the mixed film is formed in a region smaller than the spot diameter of the irradiated converged optical beam.

17. A method for forming micropatterns as claimed in Claim 7,
15 wherein the transparent film forms an antireflection structure with respect to the irradiated converged optical beam.

18. A method for forming micropatterns as claimed in Claim 17, wherein the transparent film is made of AlN.

19. A method for forming micropatterns as claimed in Claim 6 or
20 7, wherein the substrate is made of Si or SiO₂, and the metallic film is made of one selected from the group consisting of Al, Co, and Pd.

20. A method for forming micropatterns as claimed in Claim 4, wherein the substrate is selectively etched simultaneously with the etching of the mask layer, or after etching the mask layer.

25 21. A method for forming micropatterns as claimed in Claim 4 or

20, wherein the mixed layer is formed in a region smaller than the spot diameter of the irradiated converged optical beam.

22. A method for forming micropatterns as claimed in Claim 4 or 20, wherein after forming the metallic film, a transparent film is formed
5 on the metallic film before irradiating the converged optical beam.

23. A method for forming micropatterns as claimed in Claim 22, wherein the metallic film and the transparent film form an antireflection structure with respect to the irradiated converged optical beam.

24. A method for forming micropatterns as claimed in Claim 22,
10 wherein the transparent film is made of AlN.

25. A method for forming micropatterns as claimed in Claim 4 or 20, wherein the mask layer is made of Si, SiN, or SiO₂, and the metallic film is made of Al, Co, Fe, Ni, Pd, or Ti.

26. A method for forming micropatterns as claimed in Claim 4 or
15 20, wherein the remaining mixed layer is selectively removed by sputter etching.

27. A method for forming micropatterns as claimed in Claim 3, wherein the mixed film is formed in a region smaller than the spot diameter of the irradiated converged optical beam.

20 28. A method for forming micropatterns as claimed in Claim 3 or 27, wherein the heat-sensitive multilayer film has a multilayered film structure comprising at least one metallic film and at least one non-metallic film which are alternately laminated, and the mixed film is formed by alloydizing the metallic film and the non-metallic film
25 elevated to the predetermined temperature or higher.

29. A method for forming micropatterns as claimed in Claim 3 or 27, wherein, after forming the heat-sensitive multilayer film, a transparent film is formed on the heat-sensitive multilayer film before forming the mixed film.

5 30. A method for forming micropatterns as claimed in Claim 29, wherein the heat-sensitive multilayer film and the transparent film form an antireflection structure with respect to the irradiated converged optical beam.

10 31. A method for forming micropatterns as claimed in Claim 28, wherein said substrate is made of Si or SiO₂, said metallic film is made of Al, Co, or Pd, and the non-metallic film is made of Si or SiO₂.

 32. A method for forming micropatterns as claimed in Claim 29, wherein the transparent film is made of AlN.

15 33. A method for forming micropatterns as claimed in Claim 3 or 27, wherein the method further comprises, after selectively removing the portion of the heat-sensitive multilayer film other than the mixed film, etching a region of the substrate having no mixed film formed thereon by using the remaining mixed film as a mask.

20 34. A method for forming micropatterns as claimed in Claim 33, wherein the method further comprises, after etching the region of the substrate, selectively removing the remaining mixed film by sputter etching.

 35. An optical disk master produced by using the method for forming micropatterns as claimed in any one of Claims 1 to 7.

25 36. An optical disk stamper produced by using the optical disk

master as claimed in Claim 35.

37. A work stamper for optical disks produced by forming an
electrocasted film using the optical disk stamper as claimed in Claim
45 as an electrode, and peeling off the electrocasted film from the
5 optical disk stamper.

38. An optical disk produced by using the optical disk stamper
as claimed in Claim 36.

39. An optical disk produced by using the optical disk stamper
as claimed in Claim 37.

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